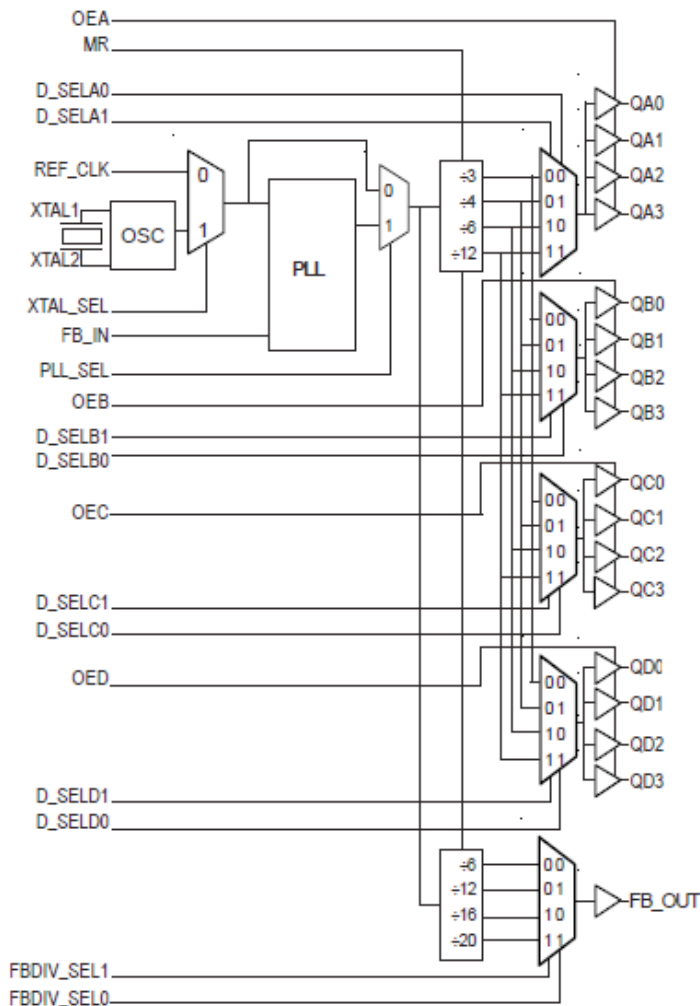


## Description

The 87611 is a low voltage, low skew PCI / PCI-X clock generator. The device has a selectable REF\_CLK or crystal input. The REF\_CLK input accepts LVCMOS or LVTTTL input levels. The 87611 has a fully integrated PLL along with frequency configurable clock and feedback outputs for multiplying and regenerating clocks with “zero delay” Using a 20MHz or 25MHz crystal or a 33.333MHz or 66.666MHz reference frequency, the 87611 will generate output frequencies of 33.333MHz, 66.666MHz, 100MHz and 133.333MHz simultaneously.

The low impedance LVCMOS/LVTTTL outputs of the 87611 are designed to drive 50Ω series or parallel terminated transmission lines.

## Block Diagram



## Features

- Fully integrated PLL
- Seventeen LVCMOS/LVTTTL outputs, 15Ω typical output impedance
- Selectable crystal oscillator interface or LVCMOS/LVTTTL REF\_CLK
- Maximum output frequency: 166.67MHz
- Maximum crystal input frequency: 40MHz
- Maximum REF\_CLK input frequency: 83.33MHz
- Individual banks with selectable output dividers for generating 33.333MHz, 66.66MHz, 100MHz and 133.333MHz simultaneously
- Separate feedback control for generating PCI / PCI-X frequencies from a 20MHz or 25MHz crystal or 33.333MHz or 66.666MHz reference frequency
- Cycle-to-cycle jitter: 70ps (maximum)
- Period jitter, RMS: 17ps (maximum)
- Output skew: 250ps (maximum)
- Bank skew: 50ps (maximum)
- Static phase offset: 0 ± 150ps (maximum)
- Full 3.3V or 3.3V core, 2.5V multiple output supply modes
- -40°C to 85°C ambient operating temperature
- Available in both standard and lead-free RoHS-compliant packages

## Pin Assignments

Figure 1. 10mm x 10mm x 1.4mm, 64-Lead TQFP (Top View)

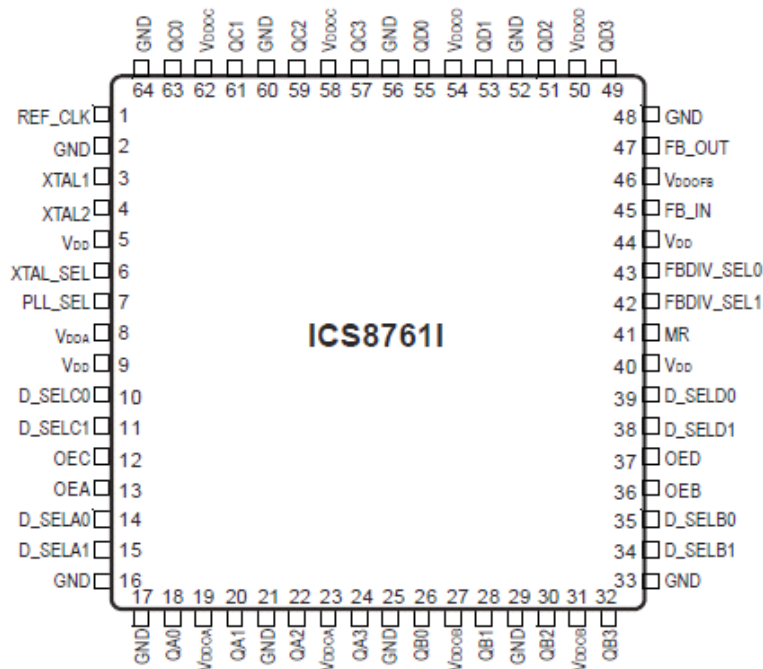


Table 1. Pin Descriptions

Number	Name	Type <sup>[a]</sup>		Description
1	REF_CLK	Input	Pulldown	Reference clock input. LVCMOS / LVTTTL interface levels.
2, 16, 17, 21, 25, 29, 33, 48, 52, 56, 60, 64	GND	Power		Power supply ground.
3, 4	XTAL1, XTAL2	Input		Crystal oscillator interface. XTAL1 is the input. XTAL2 is the output.
5, 9, 40, 44	V <sub>DD</sub>	Power		Core supply pins.
6	XTAL_SEL	Input	Pullup	Selects between crystal oscillator or reference clock as the PLL reference source. Selects XTAL inputs when HIGH. Selects REF_CLK when LOW. LVCMOS / LVTTTL interface levels.
7	PLL_SEL	Input	Pullup	Selects between PLL and bypass mode. When HIGH, selects PLL. When LOW, selects reference clock. LVCMOS / LVTTTL interface levels.
8	V <sub>DDA</sub>	Power		Analog supply pin. See Applications Note for filtering.
10, 11	D_SELCO, D_SELCO	Input	Pulldown	Selects divide value for Bank C outputs as described in Table 3. LVCMOS / LVTTTL interface levels.
12	OEC	Input	Pullup	Determines state of Bank C outputs. When HIGH, outputs are enabled. When LOW, outputs are disabled. LVCMOS / LVTTTL interface levels.
13	OEA	Input	Pullup	Determines state of Bank A outputs. When HIGH, outputs are enabled. When LOW, outputs are disabled. LVCMOS / LVTTTL interface levels.

Table 1. Pin Descriptions

Number	Name	Type <sup>[a]</sup>		Description
		Input	Pullup/Pulldown	
14, 15	D_SELA0, D_SELA1	Input	Pulldown	Selects divider value for Bank A outputs as described in <a href="#">Table 3</a> . LVCMOS / LVTTTL interface levels.
18, 20, 22, 24	QA0, QA1, QA2, QA3	Output		Bank A clock outputs. 15Ω typical output impedance. LVCMOS / LVTTTL interface levels.
19, 23	V <sub>DDOA</sub>	Power		Output supply pins for Bank A outputs.
26, 28, 30, 32	QB0, QB1, QB2, QB3	Output		Bank B clock outputs. 15Ω typical output impedance. LVCMOS / LVTTTL interface levels.
27, 31	V <sub>DDOB</sub>	Power		Output supply pins for Bank B outputs.
34, 35	D_SELB1, D_SELB0	Input	Pulldown	Selects divider value for Bank B outputs as described in <a href="#">Table 3</a> . LVCMOS / LVTTTL interface levels.
36	OEB	Input	Pullup	Determines state of Bank B outputs. When HIGH, outputs are enabled. When LOW, outputs are disabled. LVCMOS / LVTTTL interface levels.
37	OED	Input	Pullup	Determines state of Bank D outputs. When HIGH, outputs are enabled. When LOW, outputs are disabled. LVCMOS / LVTTTL interface levels.
38, 39	D_SELD1, D_SELD0	Input	Pulldown	Selects divider value for Bank D outputs as described in <a href="#">Table 3</a> . LVCMOS / LVTTTL interface levels.
41	MR	Input	Pulldown	Active HIGH Master reset. When logic HIGH, the internal dividers are reset causing the outputs to go low. When logic LOW, the internal dividers and the outputs are enabled. LVCMOS / LVTTTL interface levels.
42	FBDIV_SEL1	Input	Pulldown	Selects divider value for bank feedback output as described in <a href="#">Table 3</a> . LVCMOS / LVTTTL interface levels.
43	FBDIV_SEL0	Input	Pullup	Selects divider value for bank feedback output as described in <a href="#">Table 3</a> . LVCMOS / LVTTTL interface levels.
45	FB_IN	Input	Pulldown	Feedback input to phase detector for generating clocks with “zero delay”. LVCMOS / LVTTTL interface levels.
46	V <sub>DDOFB</sub>	Power		Output supply pin for FB_Out output.
47	FB_OUT	Output		Feedback output. Connect to FB_IN. 15Ω typical output impedance. LVCMOS / LVTTTL interface levels.
49, 51, 53, 55	QD3, QD2, QD1, QD0	Output		Bank D clock outputs. 15Ω typical output impedance. LVCMOS / LVTTTL interface levels.
50, 54	V <sub>DDOD</sub>	Power		Output supply pins for Bank D outputs.
57, 59, 61, 63	QC3, QC2, QC1, QC0	Output		Bank C clock outputs. 15Ω typical output impedance. LVCMOS / LVTTTL interface levels.
58, 62	V <sub>DDOC</sub>	Power		Output supply pins for Bank C outputs.

[a] Pullup and Pulldown refer to internal input resistors. See [Table 2](#) for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$C_{IN}$	Input Capacitance			4		pF
$R_{PULLUP}$	Input Pullup Resistor				51	k $\Omega$
$R_{PULLDOWN}$	Input Pulldown Resistor				51	k $\Omega$
$C_{PD}$	Power Dissipation Capacitance (per output) <sup>[a]</sup>	$V_{DD}, V_{DDA} = 3.465V;$ $V_{DDOx} = 3.465V$			9	pF
		$V_{DD}, V_{DDA} = 3.465V;$ $V_{DDOx} = 2.625V$			11	pF
$R_{OUT}$	Output Impedance			15		$\Omega$

[a]  $V_{DDOx}$  denotes  $V_{DDOA}, V_{DDOB}, V_{DDOC}, V_{DDOD}, V_{DDOFB}$ .

Table 3. Output Control Pin Function

Inputs					Outputs			
MR	OEA	OEB	OEC	OED	QA0:QA3	QB0:QB3	QC0:QC3	QD0:QD3
1	1	1	1	1	LOW	LOW	LOW	LOW
0	1	1	1	1	Active	Active	Active	Active
X	0	0	0	0	HiZ	HiZ	HiZ	HiZ

Table 4. Operating Mode Function

Inputs	
PLL_SEL	Operating Mode
0	Bypass
1	PLL

Table 5. PLL Input Function

Inputs	
XTAL_SEL	PLL Input
0	REF_CLK
1	XTAL Oscillator

Table 6. Control Functions

Inputs <sup>[a]</sup>					Outputs		
					PLL_SEL = 1	Frequency	
D_SELx1	D_SELx0	FBDIV_SEL1	FBDIV_SELO	Reference Frequency Range (MHz)	QX0:QX3	QX0:QX3 (MHz)	FB_OUT (MHz)
0	0	0	0	41.6 - 83.33	x 2	83.33 - 166.67	41.6 - 83.33
0	0	0	1	20.83 - 41.67	x 4	83.33 - 166.67	20.83 - 41.67
0	0	1	0	15.62 - 31.25	x 5.33	83.33 - 166.67	15.62 - 31.25
0	0	1	1	12.5 - 25	x 6.67	83.33 - 166.67	12.5 - 25
0	1	0	0	41.6 - 83.33	x 1.5	62.4 - 125	41.6 - 83.33
0	1	0	1	20.83 - 41.67	x 3	62.4 - 125	20.83 - 41.67
0	1	1	0	15.62 - 31.25	x 4	62.4 - 125	15.62 - 31.25
0	1	1	1	12.5 - 25	x 5	62.4 - 125	12.5 - 25
1	0	0	0	41.6 - 83.33	x 1	41.6 - 83.33	41.6 - 83.33
1	0	0	1	20.83 - 41.67	x 2	41.6 - 83.33	20.83 - 41.67
1	0	1	0	15.62 - 31.25	x 2.67	41.6 - 83.33	15.62 - 31.25
1	0	1	1	12.5 - 25	x 3.33	41.6 - 83.33	12.5 - 25
1	1	0	0	41.6 - 83.33	÷ 2	20.8 - 41.67	41.6 - 83.33
1	1	0	1	20.83 - 41.67	÷ 1	20.8 - 41.67	20.83 - 41.67
1	1	1	0	15.62 - 31.25	x 1.33	20.8 - 41.67	15.62 - 31.25
1	1	1	1	12.5 - 25	x 1.67	20.8 - 41.67	12.5 - 25

[a] D\_SELX1 denotes D\_SELA1, D\_SELB1, D\_SELC1, and D\_SELD1. D\_SELX0 denotes D\_SELA0, D\_SELB0, D\_SELC0, and D\_SELD0.  
 QX0:QX3 denotes QA0:QA3, QB0:QB3, QC0:QC3, and QD0:QD3.

Table 7. Control Functions – PCI Configuration

Inputs <sup>[a]</sup>					Outputs		
					PLL_SEL = 1	Frequency	
D_SELx1	D_SELx0	FBDIV_SEL1	FBDIV_SELO	Reference Frequency (MHz)	QX0:QX3	QX0:QX3 (MHz)	FB_OUT (MHz)
0	0	0	0	66.67	x 2	133	66.67
0	0	0	1	33.33	x 4	133	33.33
0	0	1	0	25	x 5.33	133	25
0	0	1	1	20	x 6.67	133	20
0	1	0	0	66.67	x 1.5	100	66.67
0	1	0	1	33.33	x 3	100	33.33
0	1	1	0	25	x 4	100	25
0	1	1	1	20	x 5	100	20
1	0	0	0	66.67	x 1	66.67	66.67
1	0	0	1	33.33	x 2	66.67	33.33
1	0	1	0	25	x 2.67	66.67	25
1	0	1	1	20	x 3.33	66.67	20
1	1	0	0	66.67	÷ 2	33.33	66.67
1	1	0	1	33.33	÷ 1	33.33	33.33
1	1	1	0	25	x 1.33	33.33	25
1	1	1	1	20	x 1.67	33.33	20

[a] D\_SELX1 denotes D\_SELA1, D\_SELB1, D\_SELC1, and D\_SELD1. D\_SELX0 denotes D\_SELA0, D\_SELB0, D\_SELC0, and D\_SELD0. QX0:QX3 denotes QA0:QA3, QB0:QB3, QC0:QC3, and QD0:QD3.

## Absolute Maximum Ratings

The absolute maximum ratings are stress ratings only. Stresses greater than those listed below can cause permanent damage to the device. Functional operation of the 87611 at absolute maximum ratings is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Table 8. Absolute Maximum Ratings

Symbol	Parameter	Conditions	Minimum	Maximum	Units
$V_{DD}$	Supply Voltage			4.6	V
$V_1$	Inputs		-0.5V	$V_{DD} + 0.5\text{ V}$	V
$V_0$	Outputs		-0.5V	$V_{DDx} + 0.5\text{ V}$	V
$\theta_{JA}$	Package Thermal Impedance			41.1 (0 lfpm)	°C/W
$T_{STG}$	Storage Temperature		-65	150	°C

## DC Characteristics

Table 9. Power Supply DC Characteristics,  $V_{DD} = V_{DDA} = V_{DDOx} = 3.3\text{V} \pm 5\%$  or  $2.5\text{V} \pm 5\%$ ,  $T_A = -40^\circ$  to  $85^\circ\text{C}$

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Core Supply Voltage		3.135	3.3	3.465	V
$V_{DDA}$	Analog Supply Voltage		3.135	3.3	3.465	V
$V_{DDOx}$	Output Supply Voltage <sup>[a]</sup>		3.135	3.3	3.465	V
			2.375	2.5	2.625	V
$I_{DD}$	Power Supply Current				175	mA
$I_{DDA}$	Analog Supply Current				55	mA
$I_{DDOx}$	Output Supply Current <sup>[b]</sup>				25	mA

[a]  $V_{DDOx}$  denotes  $V_{DDOA}$ ,  $V_{DDOB}$ ,  $V_{DDOC}$ ,  $V_{DDOD}$ ,  $V_{DDOFB}$ .

[b]  $I_{DDOx}$  denotes  $I_{DDOA}$ ,  $I_{DDOB}$ ,  $I_{DDOC}$ ,  $I_{DDOD}$ ,  $I_{DDOFB}$ .

Table 10. LVCMOS/LVTTL DC Characteristics,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $V_{DDX} = 3.3V \pm 5\%$  or  $2.5V \pm 5\%$ ,  $T_A = -40^\circ$  to  $85^\circ C$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
$V_{IH}$	Input High Voltage	OEA:OED, XTAL_SEL, MR, D_SELAx, D_SELBx, FB_IN, D_SELcx, D_SELDx, PLL_SEL, FBDIV_SEL0, FBDIV_SEL1		2		$V_{DD} + 0.3$	V
		REF_CLK		2		$V_{DD} + 0.3$	V
$V_{IL}$	Input Low Voltage	OEA:OED, XTAL_SEL, MR, D_SELAx, D_SELBx, FB_IN, D_SELcx, D_SELDx, PLL_SEL, FBDIV_SEL0, FBDIV_SEL1		-0.3		0.8	V
		REF_CLK		-0.3		1.3	V
$I_{IH}$	Input High Current	D_SELAx, D_SELBx, FB_IN, MR, D_SELcx, D_SELDx, REF_CLK, FBDIV_SEL1	$V_{DD} = V_{IN} = 3.465V$ or $2.625V$			150	$\mu A$
		XTAL_SEL, PLL_SEL, FBDIV_SEL0, OEA:OED	$V_{DD} = V_{IN} = 3.465V$ or $2.625V$			5	$\mu A$
$I_{IL}$	Input Low Current	D_SELAx, D_SELBx, FB_IN, MR, D_SELcx, D_SELDx, REF_CLK, FBDIV_SEL1	$V_{DD} = 3.465V$ or $2.625V$ , $V_{IN} = 0V$	-5			$\mu A$
		XTAL_SEL, PLL_SEL, FBDIV_SEL0, OEA:OED	$V_{DD} = 3.465V$ or $2.625V$ , $V_{IN} = 0V$	-150			$\mu A$
$V_{OH}$	Output High Voltage <sup>[a]</sup>		$V_{DDOx} = 3.465V$	2.6			V
			$V_{DDOx} = 2.625V$	1.8			
$V_{OL}$	Output Low Voltage <sup>[a]</sup>		$V_{DDOx} = 3.465V$ or $2.625V$			0.5	V
$I_{OZL}$	Output Tristate Current Low			-5			$\mu A$
$I_{OZH}$	Output Tristate Current High					5	$\mu A$

[a] Outputs terminated with  $50\Omega$  to  $V_{DDOx}/2$ . For more information, see "Output Load Test Circuit" in [Parameter Measurement Information](#).

Table 11. Crystal Characteristics

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental			
Frequency		10		38	MHz
Equivalent Series Resistance (ESR)				70	$\Omega$
Shunt Capacitance			7		pF
Drive Level				1	mW



Table 12. Crystal Characteristics

	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{REF}$	Reference Frequency		12.5		83.33	MHz

Table 13. AC Characteristics,  $V_{DD} = V_{DDA} = V_{DDOx} = 3.3V \pm 5\%$ ,  $T_A = -40^\circ$  to  $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{MAX}$	Output Frequency				166.67	MHz
$t(\emptyset)$	Static Phase Offset; Note 1, 7	$f = 50MHz$	-150		150	ps
$t_{sk}(b)$	Bank Skew; Note 2, 6				50	ps
$t_{sk}(o)$	Output Skew; Note 3, 6				250	ps
$f_{jit}(cc)$	Cycle-to-Cycle Jitter; 6	$f = 50MHz$ ; Note 4, 7			70	ps
		$f = 25MHz$ XTAL, 133.3MHz out			190	ps
$f_{jit}(per)$	Period Jitter, RMS; Note 4, 6, 7, 8				17	ps
$t_L$	PLL Lock Time				1	ms
$t_R / t_F$	Output Rise/Fall Time	20 to 80%	250		800	ps
odc	Output Duty Cycle; Note 5, 7		45		55	%

Note 1: Defined as the time difference between the input reference clock and the average feedback input signal when the PLL is locked and the input reference frequency is stable. Measured from  $V_{DD} / 2$  of the input to  $V_{DDOx} / 2$  of the output.

Note 2: Defined as skew within a bank of outputs at the same voltages and with equal load conditions.

Note 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at  $V_{DDOx} / 2$ .

Note 4: Jitter performance using LVCMOS inputs.

Note 5: Measured using REF\_CLK. For XTAL input, refer to Application Note.

Note 6: This parameter is defined in accordance with JEDEC Standard 65.

Note 7: Tested with D\_SELXX = 10 (divide by 6); FBDIV\_SEL = 00 (divide by 6).

Note 8: This parameter is defined as an RMS value.

Table 14. AC Characteristics,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $V_{DDOx} = 2.5V \pm 5\%$ ,  $T_A = -40^\circ$  to  $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{MAX}$	Output Frequency				166.67	MHz
$t(\emptyset)$	Static Phase Offset; Note 1, 7	$f = 50MHz$	-350		20	ps
$t_{sk}(b)$	Bank Skew; Note 2, 6				50	ps
$t_{sk}(o)$	Output Skew; Note 3, 6				250	ps
$f_{jit}(cc)$	Cycle-to-Cycle Jitter; Note 6	$f = 50MHz$ ; Note 4, 7			70	ps
		$f = 25MHz$ XTAL, 133.3MHz out			190	ps
$f_{jit}(per)$	Period Jitter, RMS; Note 4, 6, 7, 8				17	ps
$t_L$	PLL Lock Time				1	ms
$t_R / t_F$	Output Rise/Fall Time	20 to 80%	250		800	ps
odc	Output Duty Cycle; Note 5, 7		45		55	%

Note 1: Defined as the time difference between the input reference clock and the average feedback input signal when the PLL is locked and the input reference frequency is stable. Measured from  $V_{DD}/2$  of the input to  $V_{DDOx}/2$  of the output.

Note 2: Defined as skew within a bank of outputs at the same voltages and with equal load conditions.

Note 3: Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured at  $V_{DDOx}/2$ .

Note 4: Jitter performance using LVCMOS inputs.

Note 5: Measured using REF\_CLK. For XTAL input, refer to Application Note.

Note 6: This parameter is defined in accordance with JEDEC Standard 65.

Note 7: Tested with  $D\_SELXX = 10$  (divide by 6);  $FBDIV\_SEL = 00$  (divide by 6).

Note 8: This parameter is defined as an RMS value.

## Parameter Measurement Information

Figure 2. 3.3V Core/3.3V Output Load AC Test Circuit

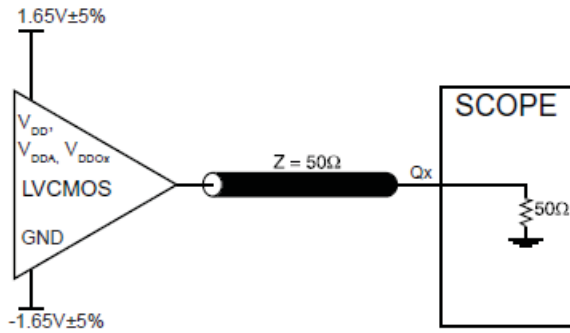


Figure 3. 3.3V Core/2.5V Output Load AC Test Circuit

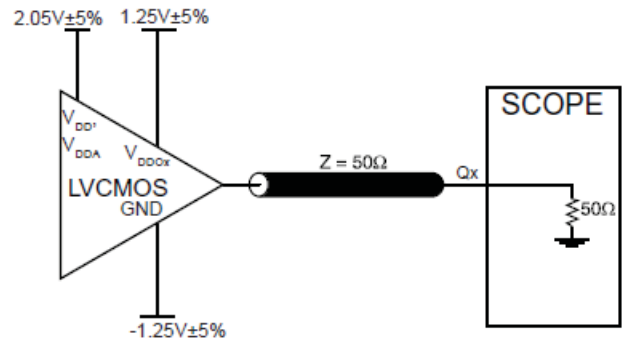


Figure 4. Output Skew



Figure 5. Bank Skew (Where X denotes outputs in the same bank)

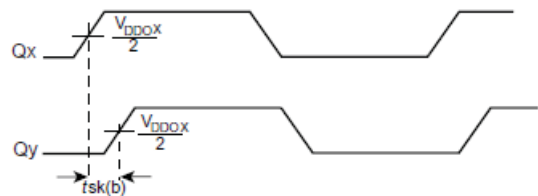


Figure 6. Cycle-to-Cycle Jitter

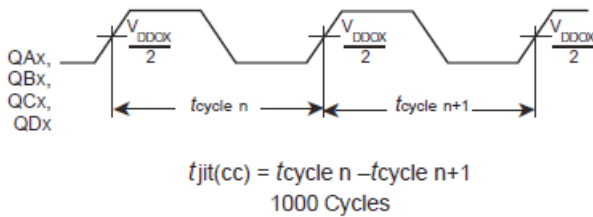


Figure 7. Static Phase Offset

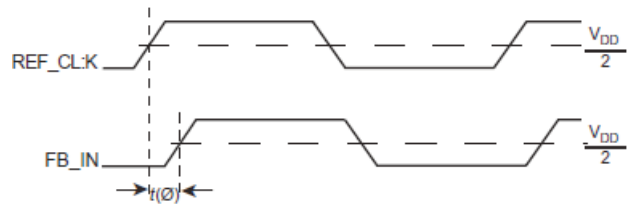


Figure 8. Output Duty Cycle/Pulse Width/Period

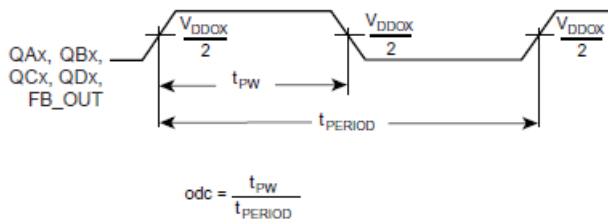
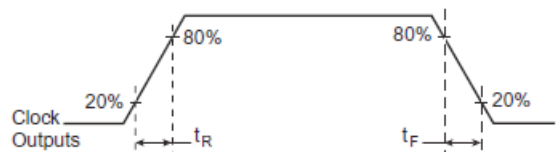


Figure 9. Output Rise/Fall Time

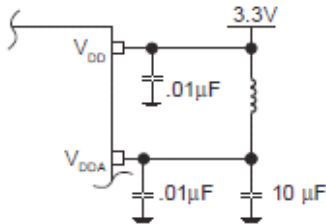


## Application Information

### Power Supply Filtering Techniques

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The 8761I provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{DD}$ ,  $V_{DDA}$ , and  $V_{DDOx}$  should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. Figure 10 illustrates how a ferrite bead along with a  $10\mu\text{F}$  and a  $0.01\text{F}$  bypass capacitor should be connected to each  $V_{DDA}$

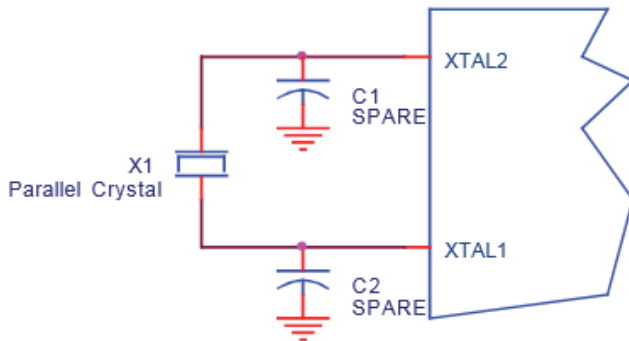
Figure 10. Power Supply Filtering



### Crystal Input Interface

The 8761I crystal interface is shown in Figure 11. While layout the PC Board, it is recommended to provide C1 and C2 spare footprints for frequency fine tuning. For an  $18\text{pF}$  parallel resonant crystal, the C1 and C2 are expected to be  $\sim 10\text{pF}$  and  $\sim 5\text{pF}$  respectively.

Figure 11. Crystal Input Interface



### Recommended for Unused Input and Output Pins

#### Inputs

##### **Crystal Input**

For applications not requiring the use of the crystal oscillator input, both XTAL\_IN and XTAL\_OUT can be left floating. Though not required, but for additional protection, a  $1\text{k}\Omega$  resistor can be tied from XTAL\_IN to ground.

##### **REF\_CLK Input**

For applications not requiring the use of the reference clock, it can be left floating. Though not required, but for additional protection, a  $1\text{k}\Omega$  resistor can be tied from the REF\_CLK to ground.

##### **LVC MOS Control Pins**

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A  $1\text{k}\Omega$  resistor can be used.

Outputs

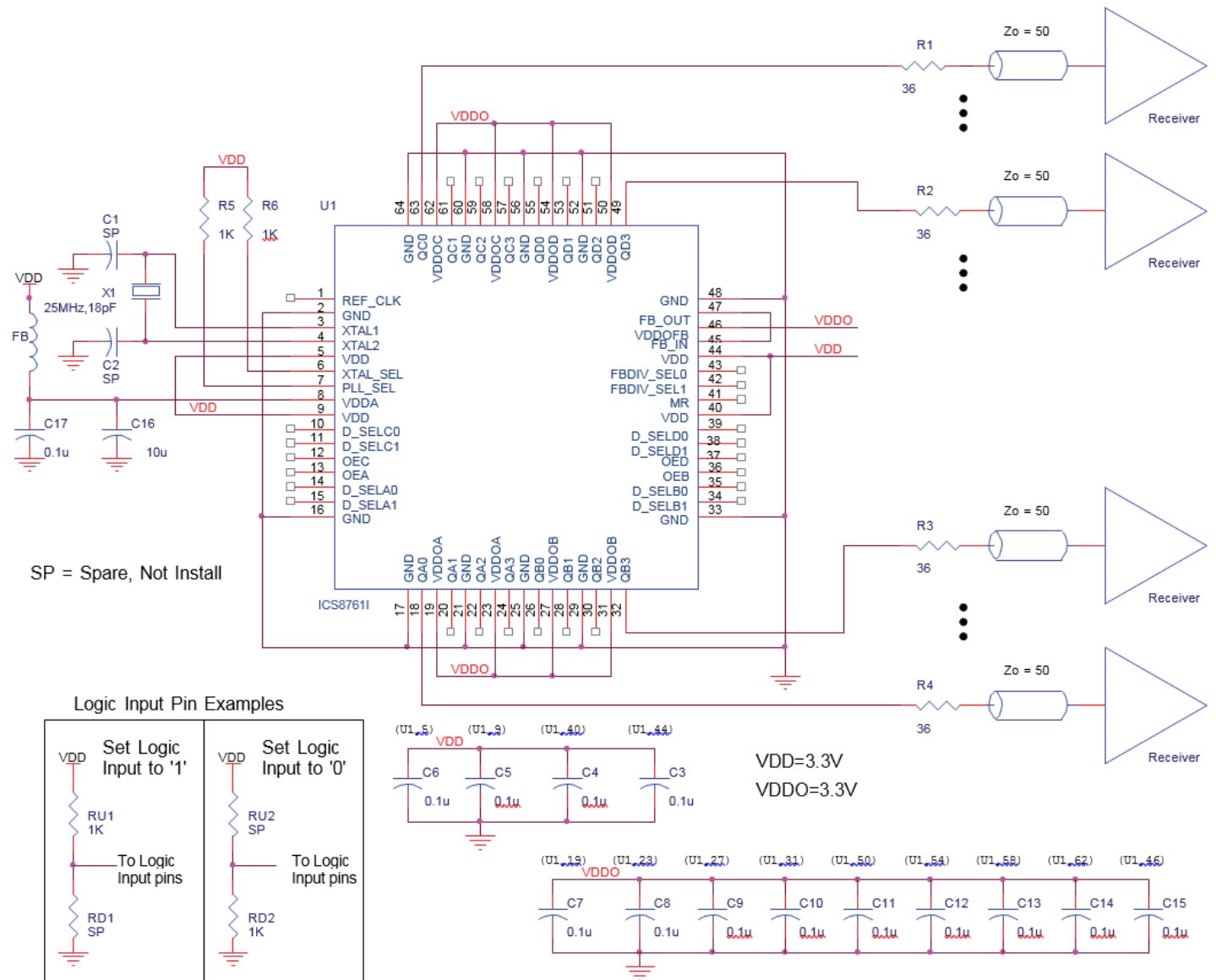
**LVC MOS Output**

All unused LVC MOS output can be left floating. We recommend that there is no trace attached.

Schematic Example

Figure 12 shows a schematic example of the 87611. In this example, the input is driven by an 18pF parallel crystal. The de-coupling capacitors should be physically located near the power pin. For 87611, the unused clock outputs can be left floating. The optional C1 and C2 are spare footprints for frequency fine tuning.

Figure 12. Schematic Example



## Reliability Information

Table 15.  $\theta_{JA}$  versus Air Flow Table for 64 Lead TQFP

$\theta_{JA}$ by Velocity (Linear Feet per Minute) <sup>[a]</sup>				
	0	1	2	Unit
Single-Layer PCB, JEDEC Standard Test Boards	58.8	48.5	43.2	°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	41.1	35.8	33.6	°C/W

[a] Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

## Transistor Count

The transistor count for the 87611 is 6040.

# Package Outline Drawings

Figure 13. Package Outline Drawings - Page 1

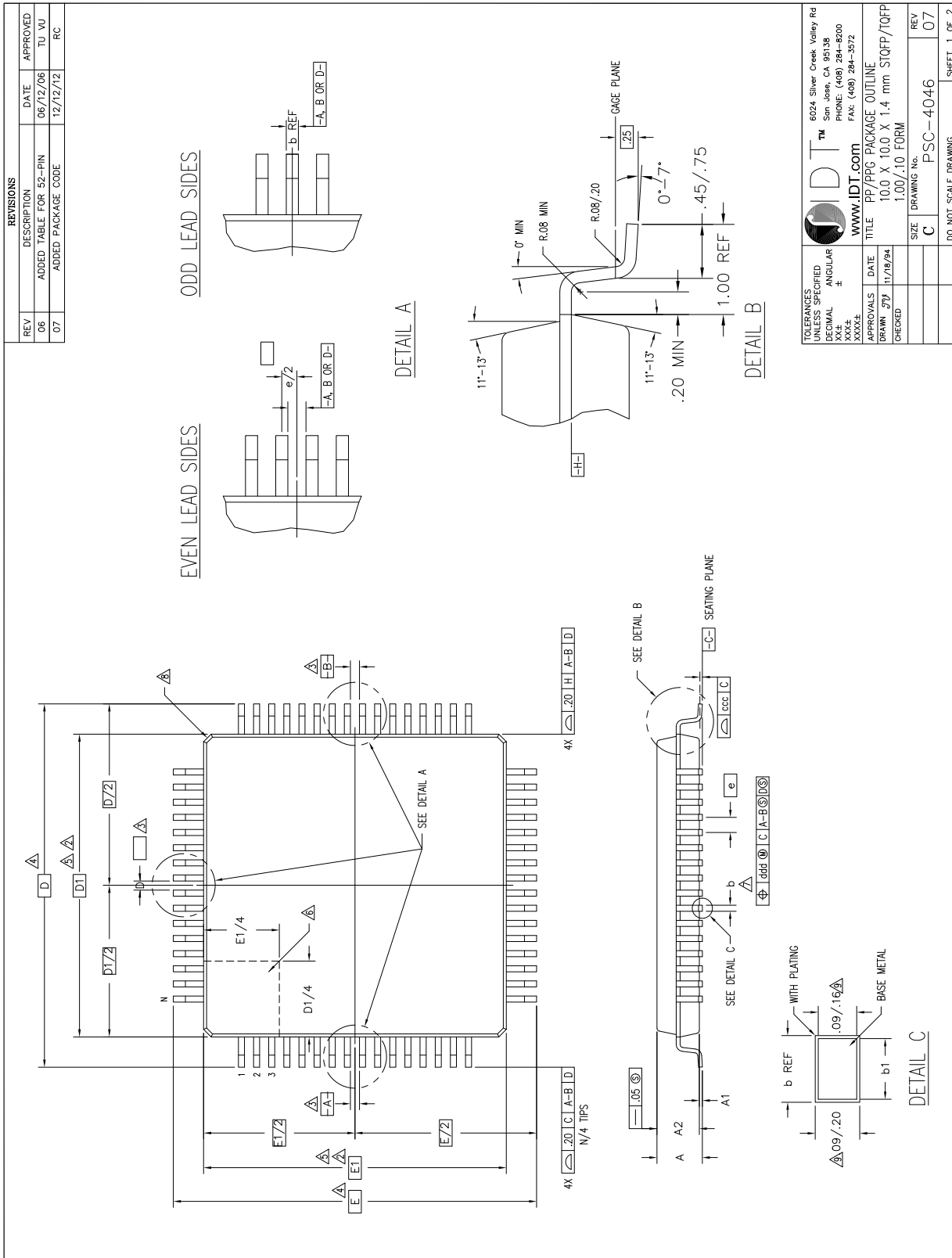
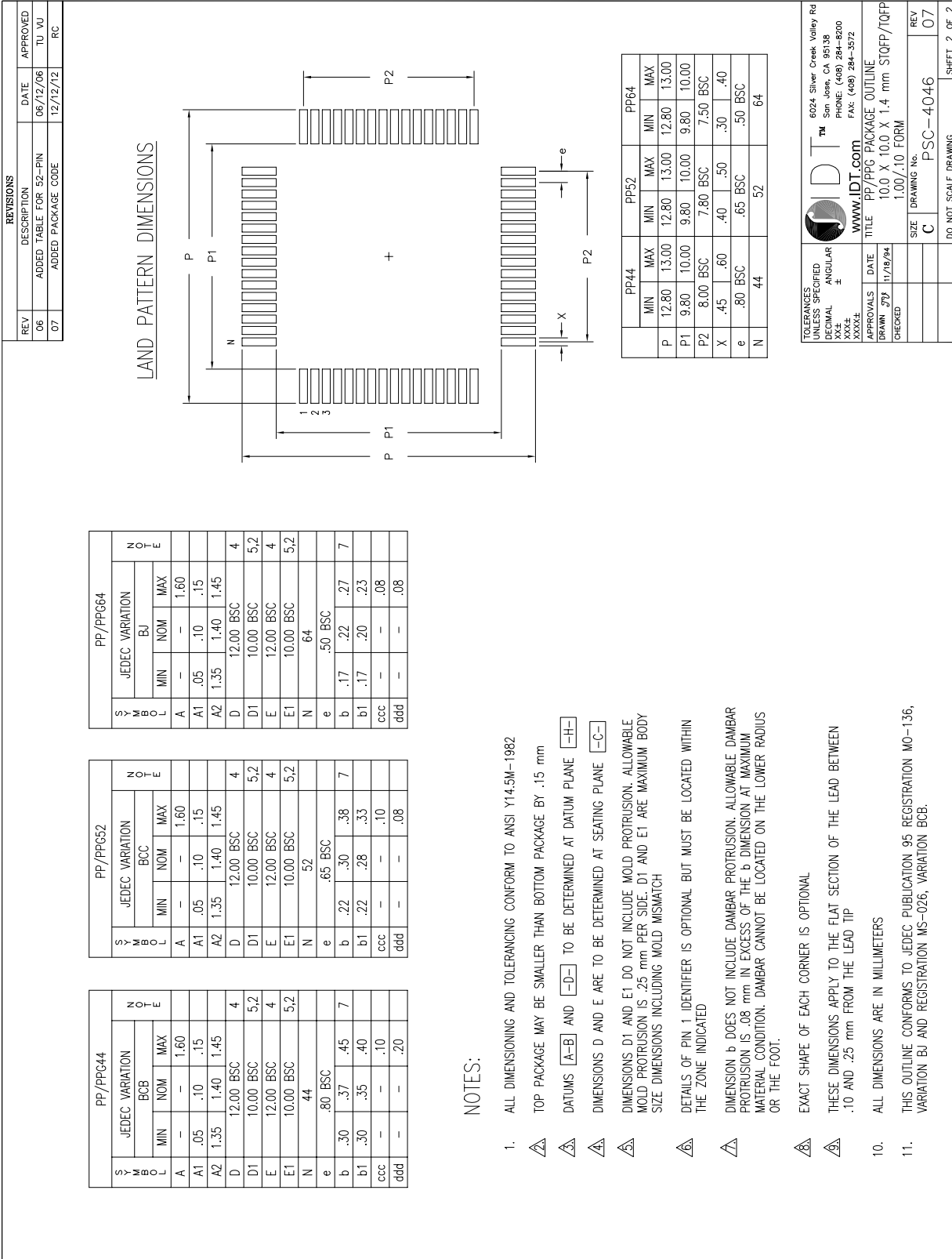


Figure 14. Package Outline Drawings - Page 2





## Ordering Information

Orderable Part Number	Marking	Package	Carrier Type	Temperature
8761CYILF	ICS8761CYILF	64 lead "Lead Free" TQFP	Tray	-40°C to +85°C
8761CYILFT	ICS8761CYILF	64 lead "Lead Free" TQFP	Tape and Reel	-40°C to +85°C

## Revision History

Revision Date	Description of Change
October 31, 2017	Fixed an incorrect part number.
October 16, 2017	<ul style="list-style-type: none"> <li>▪ Changed LQFP references to TQFP.</li> <li>▪ Updated the packaging information; however, no mechanical differences.</li> <li>▪ Completed minor changes throughout the document</li> </ul>
January 25, 2016	<ul style="list-style-type: none"> <li>▪ Removed ICS from part numbers where needed. Features Section - removed reference to leaded package.</li> <li>▪ Ordering Information - removed quantity from tape and reel. Deleted LF note below the table.</li> <li>▪ Updated header and footer.</li> </ul>
July 27, 2010	<ul style="list-style-type: none"> <li>▪ Updated the header/footer with IDT from ICS. Removed ICS prefix from Part/Order Number column. Added Contact Page.</li> </ul>
January 13, 2006	<ul style="list-style-type: none"> <li>▪ Pin Characteristics Table - changed C from 4pF max. to 4pF typical.</li> <li>▪ Crystal Characteristics Table - added Drive Level.</li> <li>▪ Power Supply Filtering Techniques - corrected last sentence in the paragraph</li> <li>▪ Corrected Power Supply Filtering diagram.</li> <li>▪ Added <i>Recommendations for Unused Input and Output Pins</i>.</li> <li>▪ Corrected Schematic Example diagram.</li> <li>▪ Ordering Information Table - added Lead-Free note.</li> </ul>
October 5, 2004	<ul style="list-style-type: none"> <li>▪ Features Section - added Lead-Free bullet. Added Crystal Section.</li> <li>▪ Ordering Information Table - added Lead-Free Part Number. Updated format throughout the datasheet.</li> </ul>

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